

Low Noise Bottom Port MEMS Microphone

DESCRIPTION

The ZTS6856S is a high quality, high performance, low power analog output bottom-ported omni-directional MEMS microphone. ZTS6856S consists of a MEMS microphone element and a preamplifier. ZTS6856S has a high SNR and flat wideband frequency response, resulting in natural sound with high intelligibility. Extra EMI filter for RF noise attenuation is built inside. Due to the built-in filter, ZTS6856S shows high immunity to EMI.

The ZTS6856S is available in a thin 2.75mm × 1.85mm × 0.9mm surface-mount package. It is reflow solder compatible with no sensitivity degradation. The ZTS6856S is Halogen and Lead free.

APPLICATIONS

- Mobile telephones
- Smart phones
- PDAs
- Digital video cameras
- Portable media devices with audio input

ORDERING INFORMATION

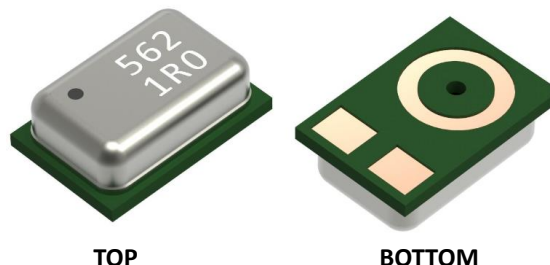
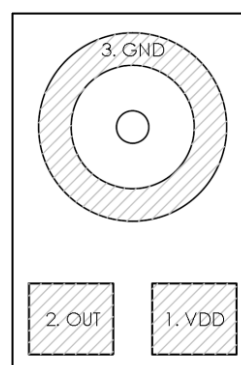
PART	RoHS	Ship, Quantity
ZTS6856S	Yes	Tape and Reel, 5.2K

FEATURES

- Small package
- Flat Frequency Response SNR of 63dBA
- Low Current
- MaxRF protection
- Ultra-Stable Performance
- Standard SMD Reflow
- Omni-directional

Pins Configuration and Description

Bottom View

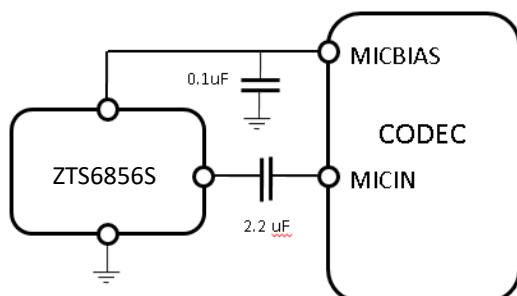


TOP

BOTTOM

Typical Applications

The ZTS6856S output can be connected to a codec microphone input or to a high input impedance gain stage. A dc-blocking capacitor is required at the output of the microphone.



Connect to Audio CODEC

Note:

All Ground pins must be connected to ground.

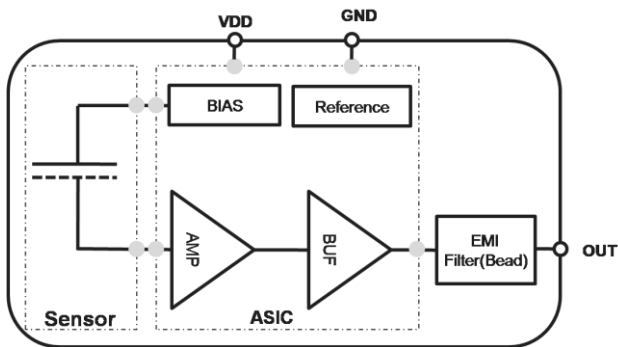
Capacitors near the microphone should not contain Class 2 dielectrics.

Absolute Maximum Ratings

V _{DD} to Ground	-0.5V to +5V
OUT to Ground	-0.3V to V _{DD} +0.3V
Input Current to Any Pin	± 5 mA
Temperature Range	-40°C to +125°C

CAUTION: Stresses above those listed in “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Functional Block Diagram



Electro-Static Discharge Sensitivity



This integrated circuit can be damaged by ESD. It is recommended that all integrated circuits be handled with proper precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure.

Pins Description

Pin	Symbol	Description
1	VDD	Power Supply.
2	OUT	Analog output signal.
3	GND	Ground

Specifications

(TA = +23°C, VDD = +1.8V, R.H. = 60%~70%, no load, VDD Decoupling cap=0.1uF unless otherwise noted.)

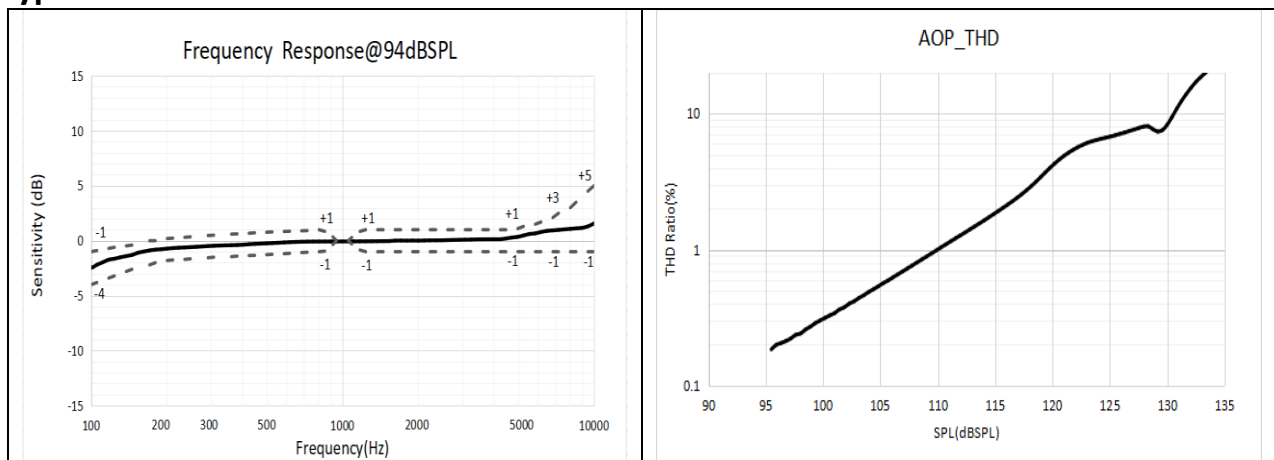
PARAMETER	Symbol	CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage ¹	V _{DD}		1.5	-	3.6	V
Supply Current ^{1,2}	I _{DD}		-	120	200	μA
Sensitivity ¹	S	94 dB SPL @ 1 kHz	-39	-38	-37	dBV/Pa
Signal to Noise Ratio	SNR	94 dB SPL @ 1 kHz, A-weighted	-	63	-	dB(A)
Total Harmonic Distortion	THD	94 dB SPL @ 1 kHz,	-	0.2	0.5	%
Acoustic Overload Point	AOP	10% THD @ 1 kHz V _{DD} = 1.8V		130		dB SPL
Power Supply Rejection Ratio	PSRR	200mVpp sine wave @ 1 kHz, V _{DD} = 1.8V	-	70	-	dB
Power Supply Rejection	PSR	100 mVpp square wave @ 217 Hz, V _{DD} = 1.8V, A-weighted	-	-90	-	dBV(A)
DC Output		V _{DD} = 1.8V	-	0.7	-	V
Output Impedance	Z _{OUT}	@ 1 kHz	-	200	350	
Directivity			Omni-directional			
Polarity		Increasing sound pressure	Increasing output pressure			

Note:

¹ 100% tested

² Maximum specifications are measured at maximum V_{DD}. Typical specifications are measured at V_{DD} = 1.8V.

Typical Performance Characteristics



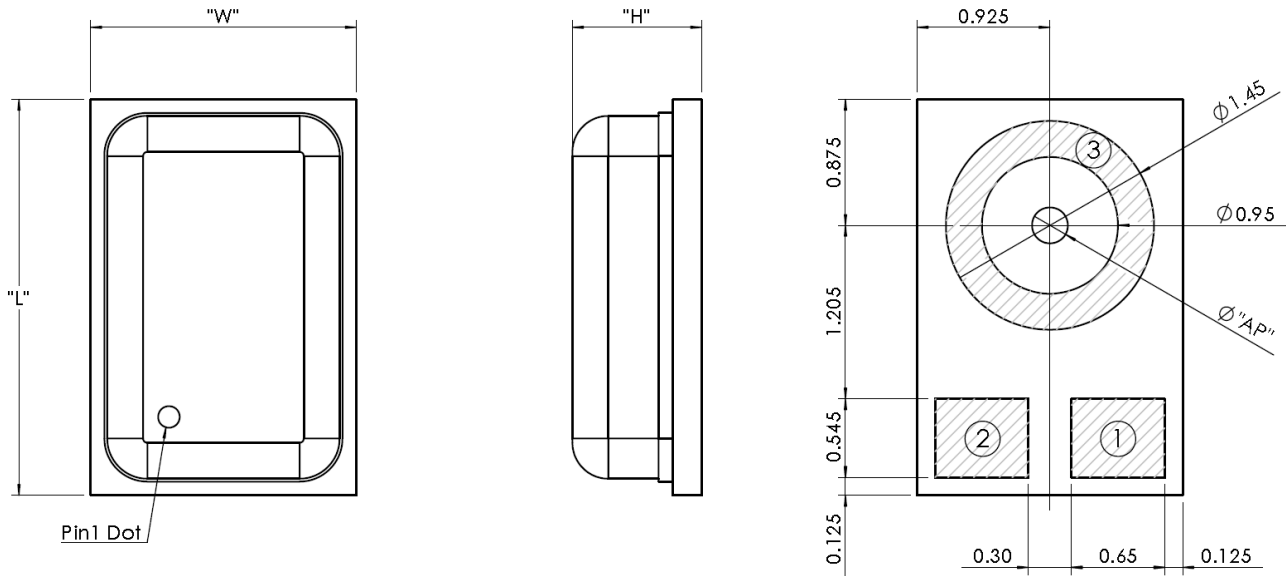
	100Hz	200Hz	300Hz	800Hz	1000Hz	1250Hz	5kHz	8kHz	10kHz
Lower	-4	-1.8	-1.5	-1	0	-1	-1	-1	-1
Upper	-1	+0.2	+0.5	+1	0	+1	+1	+3	+5

Reliability Specifications

The microphone sensitivity after stress must deviate by no more than $\pm 3\text{dB}$ from the initial value.

1.Heat Test, Operational	Temperature: $125\pm 3^{\circ}\text{C}$ Duration: 1000 hours Voltage: Applied
2.Cold Test, Operational	Temperature: $-40\pm 3^{\circ}\text{C}$ Duration: 1000 hours Voltage: Applied
3.Heat Test, Non-Operational	Temperature: $125\pm 3^{\circ}\text{C}$ Duration: 1000 hours Voltage: Not Applied
4.Cold Test, Non-Operational	Temperature: $-40\pm 3^{\circ}\text{C}$ Duration: 1000 hours Voltage: Not Applied
5.Thermal Shock Test, Non-Operational	Temperature: $-40\pm 3^{\circ}\text{C}$ and $125\pm 3^{\circ}\text{C}$ Duration: 30 minutes each, during 5 minutes ramp, 256 cycles Voltage: Not applied
6.Temperature humidity storage	Temperature: $85\pm 3^{\circ}\text{C}$ Humidity: $85\pm 3\%\text{RH}$ Duration: 1000 hours
	Temperature: $65\pm 3^{\circ}\text{C}$ Humidity: $95\pm 3\%\text{RH}$ Duration: 168 hours
7.Free Fall Test 1.5m	Placed inside test fixture and dropped on concrete from height 1.5m. 4 times by each surface and corner
8.Vibration	4 cycles of 20 to 2000 Hz sinusoidal sweep with 20G peak acceleration lasting 12 minutes in X, Y, and Z directions
9.Mechanical Shock	5 pulses of 10000g in each of the $\pm X$, $\pm Y$, and $\pm Z$ directions
10.Electrostatic Discharge Test	Capacitance: 150pF Resistance: 330 Ω Duration: 10 times Air Discharge: Level 4(+/-15kV) Direct contact discharge: Level 4 (+/-8kV)
11.Human Body Mode	± 5000 Volt
12.Charged-Device Model	± 500 Volt
13.Reflow	5 reflow cycles with peak temperature of 260°C
14. Solderability	$245\pm 5^{\circ}\text{C}$, 5sec, 95% Tin on pad surface
15. Tumble test	300 tumbles from a height of 1m onto a steel base.
16. HAST	Temperature: $130\pm 3^{\circ}\text{C}$ Humidity: $85\pm 3\%\text{RH}$ Duration: 96 hours Voltage: Applied
17. Air Blow	0.45MPa, distance 3cm, time 10s

MECHANICAL SPECIFICATIONS

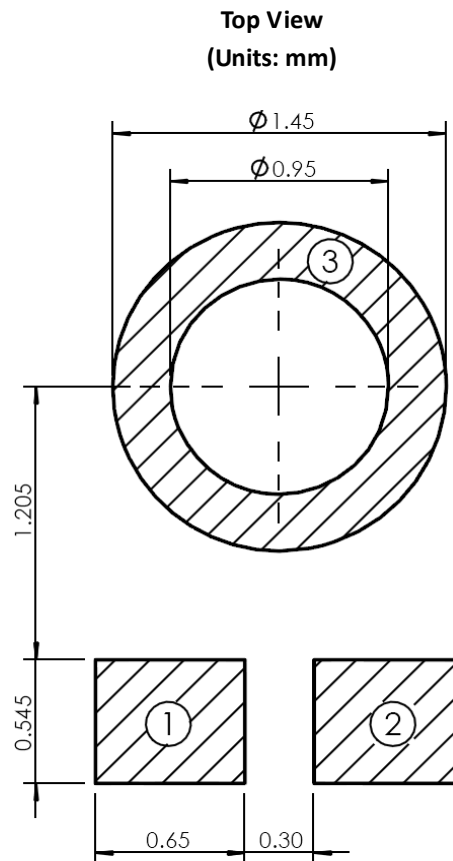


ITEM	DIMENSION	TOLERANCE	UNITS
Length (L)	2.75	± 0.100	mm
Width (W)	1.85	± 0.100	mm
Height (H)	0.90	± 0.100	mm
Acoustic Port (AP)	$\phi 0.25$	± 0.050	mm

Pin	Symbol	Description
1	VDD	Power Supply.
2	OUT	Analog output signal.
3	GND	Ground

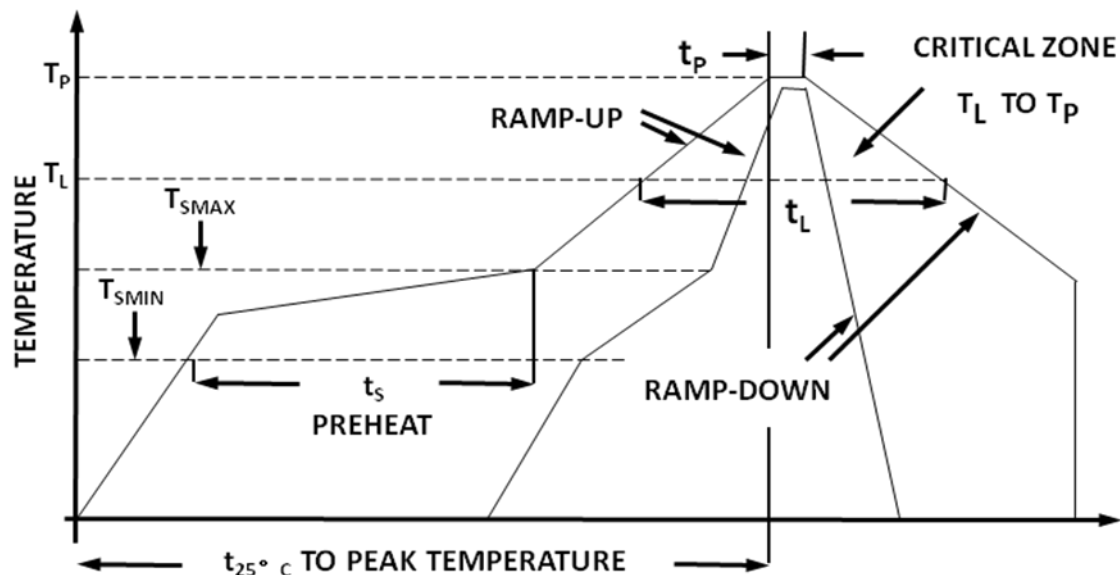
RECOMMENDED CUSTOMER LAND PATTERN

The recommended PCB land pattern for the ZTS6856S should have a 1:1 ratio to the solder pads on the microphone package. Care should be taken to avoid applying solder paste to the sound hole in PCB. The dimensions of suggested solder paste pattern refer to the land pattern which should be shrunk by 0.025 per side.



SOLDER FLOW PROFILE

The reflow profile specified in this section describes expected maximum heat exposure of components during the reflow process of NMP product PWBs. Temperature is measured on top of component. All components have to tolerate at least this profile five times (5x) without affecting electrical performance, mechanical performance or reliability.

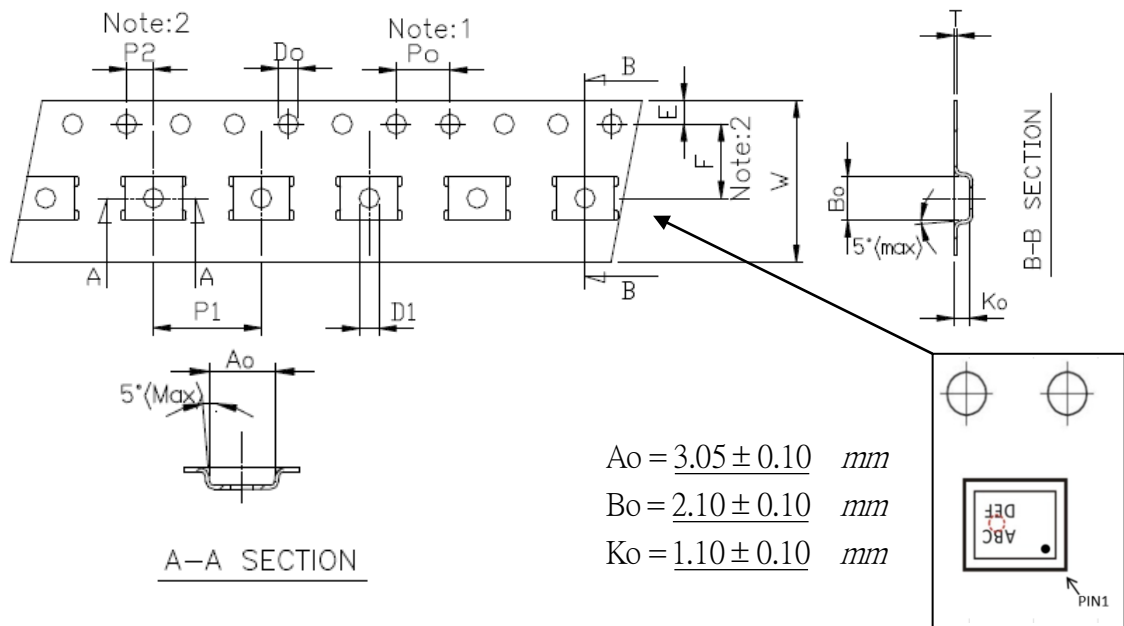
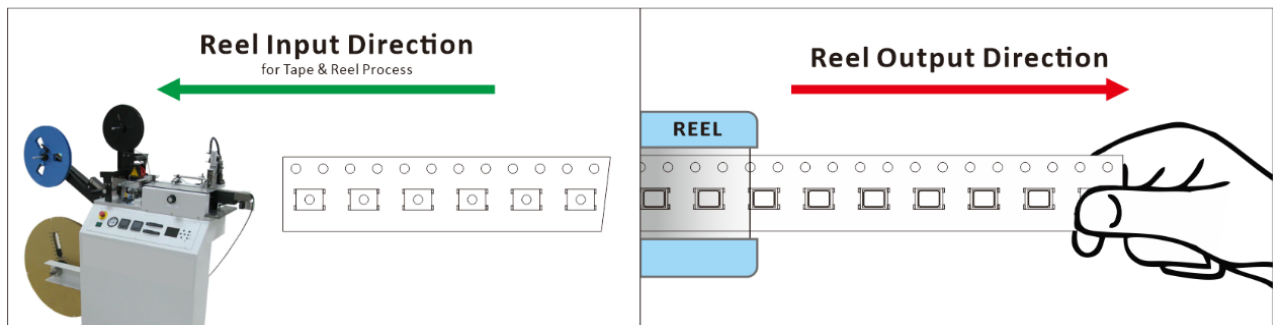


Pb-free reflow profile requirements for soldering heat resistance:

Parameter		Reference	Pb-Free
Average Ramp Rate		T_L to T_P	3°C/sec max
Preheat	Minimum Temperature	T_{SMIN}	150°C
	Maximum Temperature	T_{SMAX}	200°C
	Time	T_{SMIN} to T_{SMAX}	60sec to 180sec
Time Maintained Above	Temperature	T_L	217°C
	Time	t_L	60sec to 150sec
Peak Temperature		T_P	260°C
Time Within +5°C of Actual Peak Temperature		t_p	20 sec to 40 sec
Ramp-Down Rate		T_{peak}	6°C/sec max
Time +25°C (t_{250C}) to Peak Temperature			8 min max

ADDITIONAL NOTES: MSL (moisture sensitivity level) Class 1.

PACKAGING

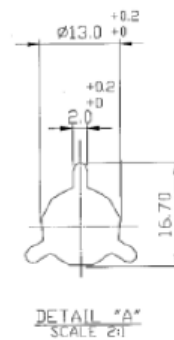
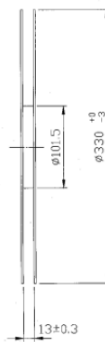
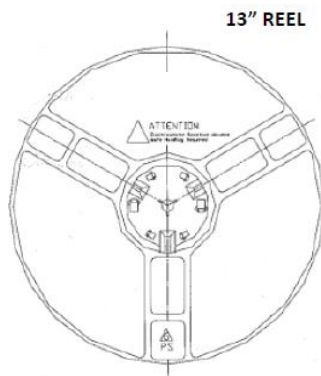


Unit: mm

Symbol	Spec.
K1	-
Po	4.0 ± 0.10
P1	8.0 ± 0.10
P2	2.0 ± 0.05
Do	1.55 ± 0.05
D1	1.50 (MIN)
E	1.75 ± 0.10
F	5.50 ± 0.05
10Po	40.0 ± 0.10
W	12.0 ± 0.20
T	0.30 ± 0.05

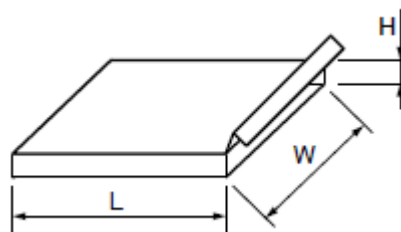
Notice:

1. 10 Sprocket hole pitch cumulative tolerance is $\pm 0.1\text{mm}$.
2. Pocket position relative to sprocket hole measured as true position of pocket not pocket hole.
3. Ao & Bo measured on a place 0.3mm above the bottom of the pocket to top surface of the carrier.
4. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
5. Carrier camber shall be not that 1mm per 100mm through a length of 250mm.



Part NO.	Reel Diameter	Quantity Per Reel	Quantity Per Inner Box	Quantity Per Outer Box
ZTS6856S	13"	5,200	5,200	46,800

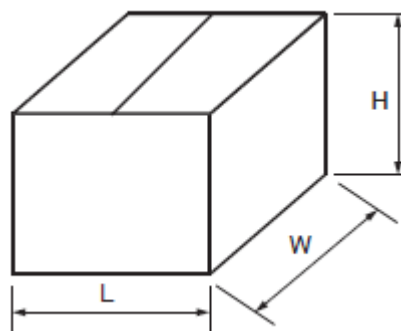
Dimensions for Inner Box



Unit: mm

L	W	H
335	339	45

Dimensions for Outer Box



Unit: mm

L	W	H
445	360	372